



## COMPLETE DDR, DDR2 AND DDR3 MEMORY POWER SOLUTION SYNCHRONOUS BUCK CONTROLLER, 3-A LDO, BUFFERED REFERENCE

### FEATURES

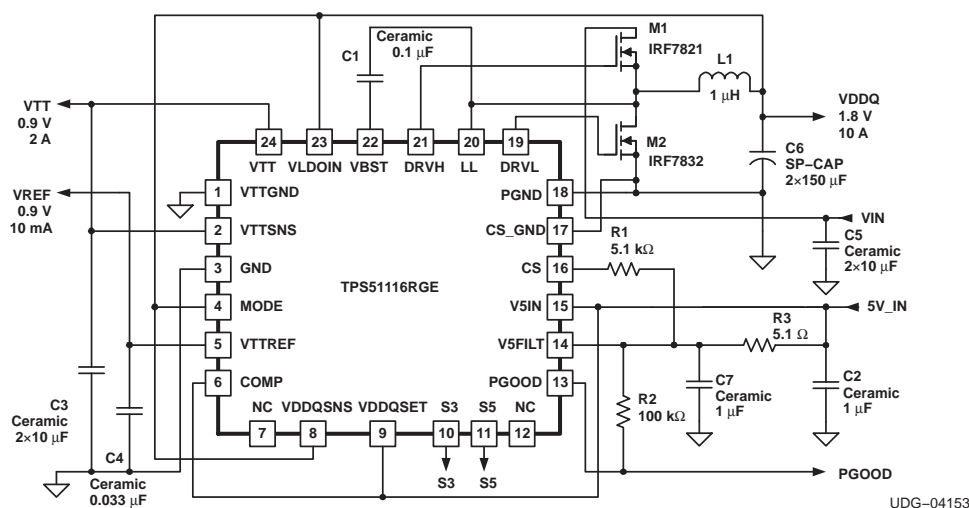
- **Synchronous Buck Controller (VDDQ)**
  - Wide-Input Voltage Range: 3.0-V to 28-V
  - D-CAP™ Mode with 100-ns Load Step Response
  - Current Mode Option Supports Ceramic Output Capacitors
  - Supports Soft-Off in S4/S5 States
  - Current Sensing from  $R_{DS(on)}$  or Resistor
  - 2.5-V (DDR), 1.8-V (DDR2), Adjustable to 1.5-V (DDR3) or Output Range 0.75-V to 3.0-V
  - Equipped with Powergood, Overvoltage Protection and Undervoltage Protection
- **3-A LDO (VTT), Buffered Reference (VREF)**
  - Capable to Sink and Source 3 A
  - LDO Input Available to Optimize Power Losses
  - Requires only 20- $\mu$ F Ceramic Output Capacitor
  - Buffered Low Noise 10-mA VREF Output
  - Accuracy 20 mV for both VREF and VTT
  - Supports High-Z in S3 and Soft-Off in S4/S5
  - Thermal Shutdown

### DESCRIPTION

The TPS51116 provides a complete power supply for DDR/SSTL-2, DDR2/SSTL-18, and DDR3 memory systems. It integrates a synchronous buck controller with a 3-A sink/source tracking linear regulator and buffered low noise reference. The TPS51116 offers the lowest total solution cost in systems where space is at a premium. The TPS51116 synchronous controller runs fixed 400kHz pseudo-constant frequency PWM with an adaptive on-time control that can be configured in D-CAP™ Mode for ease of use and fastest transient response or in current mode to support ceramic output capacitors. The 3-A sink/source LDO maintains fast transient response only requiring 20- $\mu$ F ( $2 \times 10 \mu$ F) of ceramic output capacitance. In addition, the LDO supply input is available externally to significantly reduce the total power losses. The TPS51116 supports all of the sleep state controls placing VTT at high-Z in S3 (suspend to RAM) and discharging VDDQ, VTT and VTTREF (soft-off) in S4/S5 (suspend to disk). TPS51116 has all of the protection features including thermal shutdown and is offered in both a 20-pin HTSSOP PowerPAD™ package and 24-pin 4" QFN.

### APPLICATIONS

- DDR/DDR2/DDR3 Memory Power Supplies
- SSTL-2 SSTL-18 and HSTL Termination



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

**ORDERING INFORMATION<sup>(1)</sup>**

T <sub>A</sub>	PACKAGE	ORDERABLE PART NUMBER	PINS	OUTPUT SUPPLY	MINIMUM ORDER QUANTITY
-40°C to 85°C	PLASTIC HTSSOP PowerPAD (PWP)	TPS51116PWP	20	Tube	70
		TPS51116PWPR		Tape-and-reel	2000
		TPS51116PWPRG4		Tape-and-reel	2000
	PLASTIC QUAD FLAT PACK (QFN)	TPS51116RGE	24	Tube	90
		TPS51116RGER		Large tape-and-reel	3000
		TPS51116RGET		Small tape-and-reel	250

(1) All packaging options have Cu NIPDAU lead/ball finish.

**ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>**

over operating free-air temperature range unless otherwise noted

		TPS51116	UNITS
V <sub>IN</sub> Input voltage range	VBST	-0.3 to 36	V
	VBST wrt LL	-0.3 to 6	
	CS, MODE, S3, S5, VTTSENS, VDDQSNS, V5IN, VLDOIN, VDDQSET, V5FILT	-0.3 to 6	
	PGND, VTTGND, CS_GND	-0.3 to 0.3	
V <sub>OUT</sub> Output voltage range	DRVH	-1.0 to 36	V
	LL	-1.0 to 30	
	COMP, DRVL, PGOOD, VTT, VTTREF	-0.3 to 6	
T <sub>A</sub> Operating ambient temperature range		-40 to 85	°C
T <sub>stg</sub> Storage temperature		-55 to 150	

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. All voltage values are with respect to the network ground terminal unless otherwise noted.

**DISSIPATION RATINGS**

PACKAGE	T <sub>A</sub> < 25°C POWER RATING (W)	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C (mW/°C)	T <sub>A</sub> = 85°C POWER RATING (W)
20-pin PWP	2.53	25.3	1.01
24-pin RGE	2.20	22.0	0.88

**RECOMMENDED OPERATING CONDITIONS**

		<b>MIN</b>	<b>MAX</b>	<b>UNIT</b>
Supply voltage, V5IN, V5FILT		4.75	5.25	V
Voltage range	VBST, DRVH	-0.1	34	V
	LL	-0.6	28	
	VLDOIN, VTT, VTTSNS, VDDQSNS	-0.1	3.6	
	VTTREF	-0.1	1.8	
	PGND, VTTGND, CS_GND	-0.1	0.1	
	S3, S5, MODE, VDDQSET, CS, COMP, PGOOD, DRVL	-0.1	5.25	
Operating free-air temperature, T <sub>A</sub>		-40	85	°C

**ELECTRICAL CHARACTERISTICS**

over operating free-air temperature range,  $V_{V5IN} = 5\text{ V}^{(1)}$ , VLDOIN is connected to VDDQ output (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>SUPPLY CURRENT</b>						
$I_{V5IN1}$	Supply current 1, V5IN <sup>(1)</sup>	$T_A = 25^\circ\text{C}$ , No load, $V_{S3} = V_{S5} = 5\text{ V}$ , COMP connected to capacitor		0.8	2	mA
$I_{V5IN2}$	Supply current 2, V5IN <sup>(1)</sup>	$T_A = 25^\circ\text{C}$ , No load, $V_{S3} = 0\text{ V}$ , $V_{S5} = 5\text{ V}$ , COMP connected to capacitor		300	600	$\mu\text{A}$
$I_{V5IN3}$	Supply current 3, V5IN <sup>(1)</sup>	$T_A = 25^\circ\text{C}$ , No load, $V_{S3} = 0\text{ V}$ , $V_{S5} = 5\text{ V}$ , $V_{COMP} = 5\text{ V}$		240	500	
$I_{V5INSDN}$	Shutdown current, V5IN <sup>(1)</sup>	$T_A = 25^\circ\text{C}$ , No load, $V_{S3} = V_{S5} = 0\text{ V}$		0.1	1.0	
$I_{VLDOIN1}$	Supply current 1, VLDOIN	$T_A = 25^\circ\text{C}$ , No load, $V_{S3} = V_{S5} = 5\text{ V}$		1	10	mA
$I_{VLDOIN2}$	Supply current 2, VLDOIN	$T_A = 25^\circ\text{C}$ , No load, $V_{S3} = 5\text{ V}$ , $V_{S5} = 0\text{ V}$ ,		0.1	10	
$I_{VLDOINSDN}$	Standby current, VLDOIN	$T_A = 25^\circ\text{C}$ , No load, $V_{S3} = V_{S5} = 0\text{ V}$		0.1	1.0	
<b>VTTREF OUTPUT</b>						
$V_{VTTREF}$	Output voltage, VTTREF		$V_{VDDQSNS}/2$			V
$V_{VTTREFTOL}$	Output voltage tolerance	$-10\text{ mA} < I_{VTTREF} < 10\text{ mA}$ , $V_{VDDQSNS} = 2.5\text{ V}$ , Tolerance to $V_{VDDQSNS}/2$	-20		20	mV
		$-10\text{ mA} < I_{VTTREF} < 10\text{ mA}$ , $V_{VDDQSNS} = 1.8\text{ V}$ , Tolerance to $V_{VDDQSNS}/2$	-18		18	
		$-10\text{ mA} < I_{VTTREF} < 10\text{ mA}$ , $V_{VDDQSNS} = 1.5\text{ V}$ , Tolerance to $V_{VDDQSNS}/2$	-15		15	
$V_{VTTREFSRC}$	Source current	$V_{VDDQSNS} = 2.5\text{ V}$ , $V_{VTTREF} = 0\text{ V}$	-20	-40	-80	mA
$V_{VTTREFSNK}$	Sink current	$V_{VDDQSNS} = 2.5\text{ V}$ , $V_{VTTREF} = 2.5\text{ V}$	20	40	80	
<b>VTT OUTPUT</b>						
$V_{VTTSENS}$	Output voltage, VTT	$V_{S3} = V_{S5} = 5\text{ V}$ , $V_{VLDOIN} = V_{VDDQSNS} = 2.5\text{ V}$		1.25		V
		$V_{S3} = V_{S5} = 5\text{ V}$ , $V_{VLDOIN} = V_{VDDQSNS} = 1.8\text{ V}$		0.9		
		$V_{S3} = V_{S5} = 5\text{ V}$ , $V_{VLDOIN} = V_{VDDQSNS} = 1.5\text{ V}$		0.75		
$V_{VTTTOL25}$	VTT output voltage tolerance to VTTREF	$V_{S3} = V_{S5} = 5\text{ V}$ , $I_{VTT} = 0\text{ A}$	-20		20	mV
		$V_{S3} = V_{S5} = 5\text{ V}$ , $ I_{VTT}  < 1.5\text{ A}$	-30		30	
		$V_{S3} = V_{S5} = 5\text{ V}$ , $ I_{VTT}  < 3\text{ A}$	-40		40	
$V_{VTTTOL18}$	VTT output voltage tolerance to VTTREF	$V_{S3} = V_{S5} = 5\text{ V}$ , $I_{VTT} = 0\text{ A}$	-20		20	
		$V_{S3} = V_{S5} = 5\text{ V}$ , $ I_{VTT}  < 1\text{ A}$	-30		30	
		$V_{S3} = V_{S5} = 5\text{ V}$ , $ I_{VTT}  < 2\text{ A}$	-40		40	
$V_{VTTTOL15}$	VTT output voltage tolerance to VTTREF	$V_{S3} = V_{S5} = 5\text{ V}$ , $I_{VTT} = 0\text{ A}$	-20		20	
		$V_{S3} = V_{S5} = 5\text{ V}$ , $ I_{VTT}  < 1\text{ A}$	-30		30	
		$V_{S3} = V_{S5} = 5\text{ V}$ , $ I_{VTT}  < 2\text{ A}$	-40		40	
$I_{VTTTOCLSRC}$	Source current limit, VTT	$V_{VLDOIN} = V_{VDDQSNS} = 2.5\text{ V}$ , $V_{VTT} = V_{VTTSENS} = 1.19\text{ V}$ , PGOOD = HI	3.0	3.8	6.0	A
		$V_{VLDOIN} = V_{VDDQSNS} = 2.5\text{ V}$ , $V_{VTT} = 0\text{ V}$	1.5	2.2	3.0	
$I_{VTTTOCLSNK}$	Sink current limit, VTT	$V_{VLDOIN} = V_{VDDQSNS} = 2.5\text{ V}$ , $V_{VTT} = V_{VTTSENS} = 1.31\text{ V}$ , PGOOD = HI	3.0	3.6	6.0	
		$V_{VLDOIN} = V_{VDDQSNS} = 2.5\text{ V}$ , $V_{VTT} = V_{VDDQ}$	1.5	2.2	3.0	
$I_{VTTLK}$	Leakage current, VTT	$V_{S3} = 0\text{ V}$ , $V_{S5} = 5\text{ V}$ , $V_{VTT} = V_{VDDQSNS}/2$	-10		10	$\mu\text{A}$
$I_{VTTBIAS}$	Input bias current, VTTSENS	$V_{S3} = 5\text{ V}$ , $V_{VTTSENS} = V_{VDDQSNS}/2$	-1	-0.1	1	$\mu\text{A}$
$I_{VTTSENSLK}$	Leakage current, VTTSENS	$V_{S3} = 0\text{ V}$ , $V_{S5} = 5\text{ V}$ , $V_{VTT} = V_{VDDQSNS}/2$	-1		1	$\mu\text{A}$
$I_{VTTDisch}$	Discharge current, VTT	$T_A = 25^\circ\text{C}$ , $V_{S3} = V_{S5} = V_{VDDQSNS} = 0\text{ V}$ , $V_{VTT} = 0.5\text{ V}$	10	17		mA

(1) V5IN references to PWP packaged devices should be interpreted as V5FILT references to RGE packaged devices.

**ELECTRICAL CHARACTERISTICS (continued)**

 over operating free-air temperature range,  $V_{VIN} = 5\text{ V}$ , VLDOIN is connected to VDDQ output (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>VDDQ OUTPUT</b>						
$V_{VDDQ}$	Output voltage, VDDQ	$T_A = 25^\circ\text{C}$ , $V_{VDDQSET} = 0\text{ V}$ , No load	2.465	2.500	2.535	V
		$0^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$ , $V_{VDDQSET} = 0\text{ V}$ , No load <sup>(2)</sup>	2.457	2.500	2.543	
		$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$ , $V_{VDDQSET} = 0\text{ V}$ , No load <sup>(2)</sup>	2.440	2.500	2.550	
		$T_A = 25^\circ\text{C}$ , $V_{VDDQSET} = 5\text{ V}$ , No load <sup>(2)</sup>	1.776	1.800	1.824	
		$0^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$ , $V_{VDDQSET} = 5\text{ V}$ , No load <sup>(2)</sup>	1.769	1.800	1.831	
		$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$ , $V_{VDDQSET} = 5\text{ V}$ , No load <sup>(2)</sup>	1.764	1.800	1.836	
		$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$ , Adjustable mode, No load <sup>(2)</sup>	0.75		3.0	
$V_{VDDQSET}$	VDDQSET regulation voltage	$T_A = 25^\circ\text{C}$ , Adjustable mode	742.5	750.0	757.5	mV
		$0^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$ , Adjustable mode	740.2	750.0	759.8	
		$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$ , Adjustable mode	738.0	750.0	762.0	
$R_{VDDQSNS}$	Input impedance, VDDQSNS	$V_{VDDQSET} = 0\text{ V}$		215		k $\Omega$
		$V_{VDDQSET} = 5\text{ V}$		180		
		Adjustable mode		460		
$I_{VDDQSET}$	Input current, VDDQSET	$V_{VDDQSET} = 0.78\text{ V}$ , COMP = Open		-0.04		$\mu\text{A}$
		$V_{VDDQSET} = 0.78\text{ V}$ , COMP = 5 V		-0.06		
$I_{VDDQDisch}$	Discharge current, VDDQ	$V_{S3} = V_{S5} = 0\text{ V}$ , $V_{VDDQSNS} = 0.5\text{ V}$ , $V_{MODE} = 0\text{ V}$	10	40		mA
$I_{VLDOINDisch}$	Discharge current, VLDOIN	$V_{S3} = V_{S5} = 0\text{ V}$ , $V_{VDDQSNS} = 0.5\text{ V}$ , $V_{MODE} = 0.5\text{ V}$		700		
<b>TRANSCONDUCTANCE AMPLIFIER</b>						
gm	Gain	$T_A = 25^\circ\text{C}$	240	300	360	$\mu\text{S}$
$I_{COMPSNK}$	COMP maximum sink current	$V_{S3} = 0\text{ V}$ , $V_{S5} = 5\text{ V}$ , $V_{VDDQSET} = 0\text{ V}$ , $V_{VDDQSNS} = 2.7\text{ V}$ , $V_{COMP} = 1.28\text{ V}$		13		$\mu\text{A}$
$I_{COMP SRC}$	COMP maximum source current	$V_{S3} = 0\text{ V}$ , $V_{S5} = 5\text{ V}$ , $V_{VDDQSET} = 0\text{ V}$ , $V_{VDDQSNS} = 2.3\text{ V}$ , $V_{COMP} = 1.28\text{ V}$		-13		
$V_{COMP HI}$	COMP high clamp voltage	$V_{S3} = 0\text{ V}$ , $V_{S5} = 5\text{ V}$ , $V_{VDDQSET} = 0\text{ V}$ , $V_{VDDQSNS} = 2.3\text{ V}$ , $V_{CS} = 0\text{ V}$	1.31	1.34	1.37	V
$V_{COMP LO}$	COMP low clamp voltage	$V_{S3} = 0\text{ V}$ , $V_{S5} = 5\text{ V}$ , $V_{VDDQSET} = 0\text{ V}$ , $V_{VDDQSNS} = 2.7\text{ V}$ , $V_{CS} = 0\text{ V}$	1.18	1.21	1.24	
<b>DUTY CONTROL</b>						
$T_{ON}$	Operating on-time	$V_{IN} = 12\text{ V}$ , $V_{VDDQSET} = 0\text{ V}$		520		ns
$T_{ON0}$	Startup on-time	$V_{IN} = 12\text{ V}$ , $V_{VDDQSNS} = 0\text{ V}$		125		
$T_{ON(min)}$	Minimum on-time	$T_A = 25^\circ\text{C}$ <sup>(2)</sup>		100		
$T_{OFF(min)}$	Minimum off-time	$T_A = 25^\circ\text{C}$ <sup>(2)</sup>		350		
<b>ZERO CURRENT COMPARATOR</b>						
$V_{ZC}$	Zero current comparator offset		-6	0	6	mV
<b>OUTPUT DRIVERS</b>						
$R_{DRVH}$	DRVH resistance	Source, $I_{DRVH} = -100\text{ mA}$		3	6	$\Omega$
		Sink, $I_{DRVH} = 100\text{ mA}$		0.9	3	
$R_{DRVL}$	DRVL resistance	Source, $I_{DRVL} = -100\text{ mA}$		3	6	
		Sink, $I_{DRVL} = 100\text{ mA}$		0.9	3	
$T_D$	Dead time	LL-low to DRVL-on <sup>(2)</sup>		10		ns
		DRVL-off to DRVH-on <sup>(2)</sup>		20		

(2) Ensured by design. Not production tested.

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